

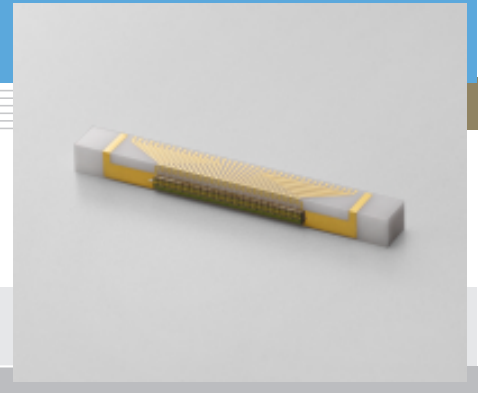
NEW

PHOTODIODE

InGaAs PIN photodiode array

G8909-01

Photodiode array for DWDM monitor

**Features**

- 250 μm pitch, 40 ch parallel readout
- Low cross-talk
- Precise chip position tolerance: ± 0.05 mm

Applications

- DWDM monitor with AWG

General ratings

Parameter	Value	Unit
Active area	$\phi 0.08$	mm
Pixel pitch	250	μm
Number of elements	40	ch

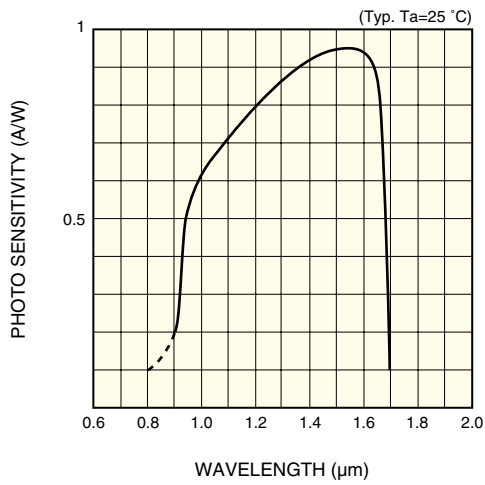
Absolute maximum ratings

Parameter	Symbol	Remark	Value	Unit
Reverse voltage	V_R Max.		6	V
Allowable input power	P_{in} Max.		10	mW
Operating temperature	T_{opr}	*	-40 to +85	$^{\circ}\text{C}$
Storage temperature	T_{stg}		-40 to +85	$^{\circ}\text{C}$

* In N_2 environment or in vacuum**Electrical and optical characteristics ($T_a=25^{\circ}\text{C}$, per 1 element)**

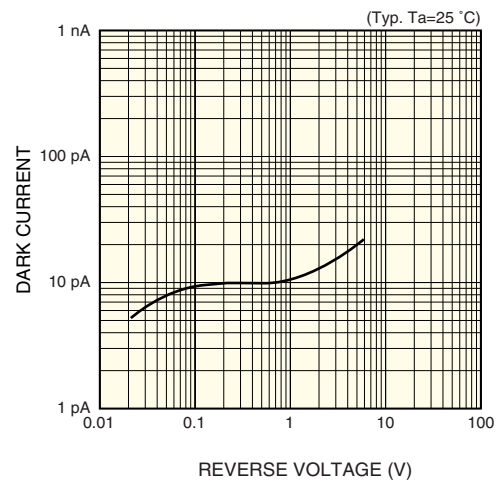
Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Spectral response range	λ		-	0.9 to 1.7	-	μm
Photo sensitivity	S	$\lambda=1.31 \mu\text{m}$	0.8	0.9	-	A/W
		$\lambda=1.55 \mu\text{m}$	0.85	0.95	-	
Photo response non-uniformity	PRNU		-	-	± 5	%
Dark current	I_D	$V_R=5$ V	-	0.02	0.2	nA
Shunt resistance	Rsh	$V_R=10$ mV	-	8	-	$\text{G}\Omega$
Terminal capacitance	C_t	$V_R=5$ V, $f=1$ MHz	-	1.4	-	pF
Cross-talk	-	$V_R=0.1$ V	-	-33	-	dB

■ Spectral response



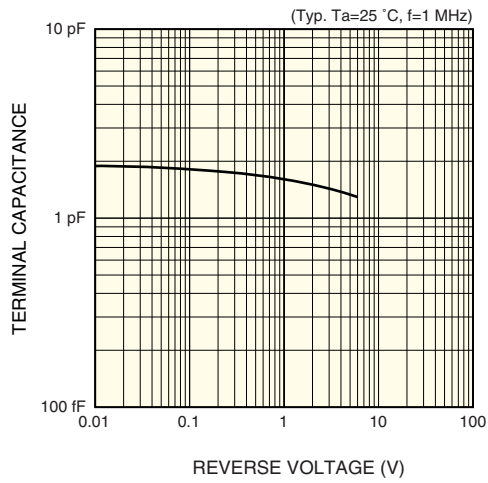
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■ Dark current vs. reverse voltage



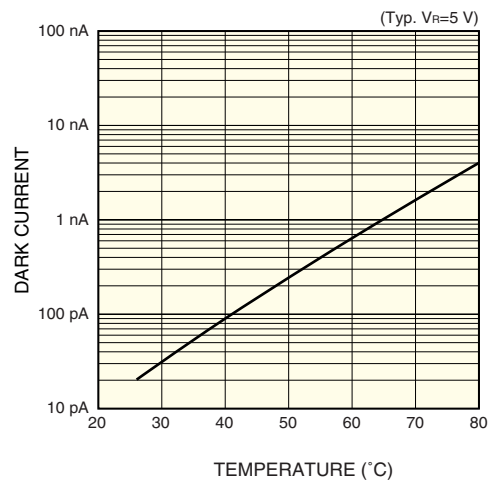
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■ Terminal capacitance vs. reverse voltage



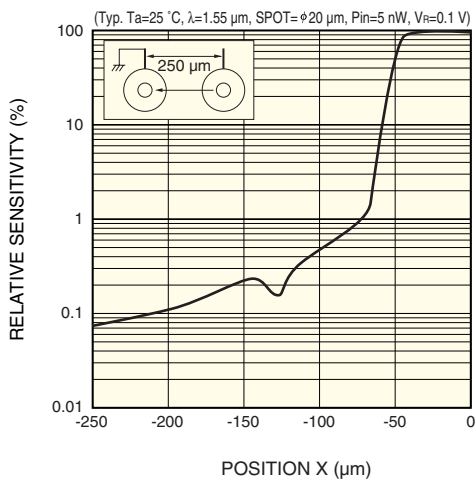
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■ Dark current vs. temperature



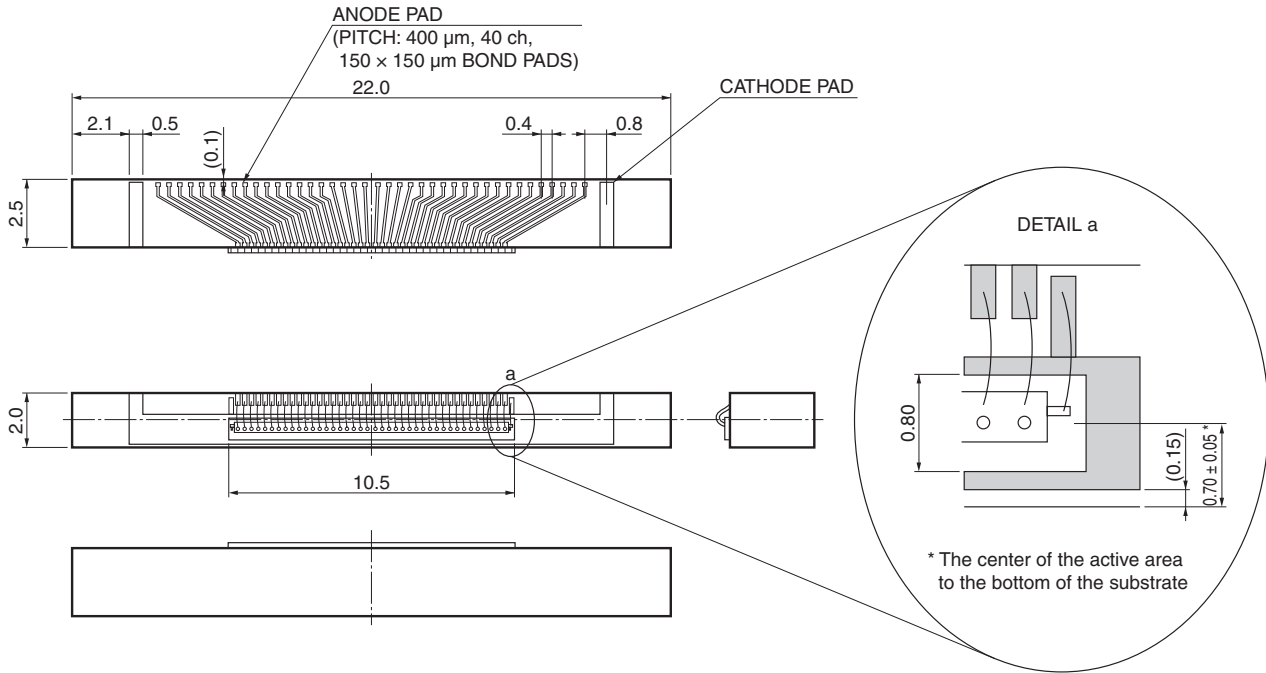
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■ Cross-talk characteristic



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■ Dimensional outline (unit: mm)



KIRDA0158EA

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HAMAMATSU PHOTONICS K.K., Solid State Division

1126-1 Ichino-cho, Hamamatsu City, 435-8558 Japan, Telephone: (81) 053-434-3311, Fax: (81) 053-434-5184, <http://www.hamamatsu.com>

U.S.A.: Hamamatsu Corporation: 360 Foothill Road, P.O.Box 6910, Bridgewater, N.J. 08807-0910, U.S.A., Telephone: (1) 908-231-0960, Fax: (1) 908-231-1218

Germany: Hamamatsu Photonics Deutschland GmbH: Arzbergerstr. 10, D-82211 Herrsching am Ammersee, Germany, Telephone: (49) 08152-3750, Fax: (49) 08152-2658

France: Hamamatsu Photonics France S.A.R.L.: 8, Rue du Saule Trapu, Parc du Moulin de Massy, 91882 Massy Cedex, France, Telephone: 33-(1) 69 53 71 00, Fax: 33-(1) 69 53 71 10

United Kingdom: Hamamatsu Photonics UK Limited: 2 Howard Court, 10 Tewin Road, Welwyn Garden City, Hertfordshire AL7 1BW, United Kingdom, Telephone: (44) 1707-294888, Fax: (44) 1707-325777

North Europe: Hamamatsu Photonics Norden AB: Smidesvägen 12, SE-171 41 Solna, Sweden, Telephone: (46) 8-509-031-00, Fax: (46) 8-509-031-01

Italy: Hamamatsu Photonics Italia S.R.L.: Strada della Moia, 1/E, 20020 Arese, (Milano), Italy, Telephone: (39) 02-935-81-733, Fax: (39) 02-935-81-741